

<b>INFORMATION DISCLOSURE STATEMENT</b>		Atty Docket: Serial No.: Applicant: Filing Date: Group:	62603 CON1 <del>NOT YET ASSIGNED</del> MEARS HEREWITH	10/7/04 783

U.S. PATENT DOCUMENTS							
Examiner Initials		Document Number	Date	Name	Class	Sub Class	Filing Date
<i>Gu</i>	AA	4,594,603	06/10/86	Holonyak, Jr.	357	16	01/24/85
	AB	4,937,204	06/26/90	Ishibashi et al.	437	110	01/4/89
	AC	4,969,031	11/06/90	Kobayashi et al.	357	63	02/3/83
	AD	5,05,887	10/08/91	Yamazaki	357	4	01/18/90
	AE	5,216,262	06/1/93	Tsu	257	17	03/2/92
	AF	5,357,119	10/18/94	Wang et al.	257	18	02/19/93
	AG	5,684,817	11/04/97	Houdre et al.	372	45	05/1/96
	AH	5,683,934	11/4/03	Candelaria	437	134	05/3/96
	AI	5,994,164	11/30/99	Fonash et al.	438	97	03/18/98
	AJ	6,058,127	05/2/00	Joannopoulos et al.	372	92	12/12/97
	AK	6,274,007	08/14/01	Smirnov et al.	204	192	03/14/00
	AL	6,281,518	08/28/01	Sato	257	13	12/3/98
	AM	6,281,532	08/28/01	Doyle et al.	257	288	06/28/99
	AN	6,344,271	02/05/02	Yadav et al.	428	402	03/23/99
	AO	6,472,685	10/29/02	Takagi	257	77	12/2/98
	AP	6,498,359	12/24/02	Schmidt et al.	257	190	05/18/01
	AQ	2003/0034529	02/20/03	Fitzgerald et al.	257	369	10/8/02
<i>Gu</i>	AR	2003/0057416	03/27/03	Currie et al.	257	19	09/20/02

FOREIGN PATENT DOCUMENTS							
		Document Number	Date	Country	Class	Sub Class	Translation
<i>Gu</i>	AS	02/103767	12/27/02	WO	H01L	21/20	
<i>Gu</i>	AT	2,347,520	09/06/00	GB	G02B	5/18	
	AU						

EXAMINER:	<i>Gu</i>	DATE CONSIDERED:	<i>7/24/04</i>
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609;  
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<b>INFORMATION DISCLOSURE STATEMENT</b>		Atty Docket: Serial No.: Applicant: Filing Date: Group:	62603_CON1 NOT YET ASSIGNED MEARS HEREWITH

<b>OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)</b>		
<i>S.M.</i>	AV	Xuan Luo et al.; "Chemical Design of Direct-Gap Light-Emitting Silicon", published July 25, 2002 by The American Physical Society; Vol. 89, Number 7
	AW	R. Tsu; University of North Carolina at Charlotte, "Phenomena in Silicon Nanostructure Devices"; published 09/06/2000 © Springer-Verlag 2000
	AX	P.D. Ye et al., "GaAs MOSFET with Oxide Gate Dielectric Grown by Atomic Layer Deposition"; © 2003 Agere Systems, March 2003
<i>S.M.</i>	AY	Novikov et al.; "Silicon-based Optoelectronics" © 1999-2003 by John Wiley & Sons, Inc.; pp/ 1-6
	AZ	
	BA	

<b>EXAMINER:</b> <i>S. M. M.</i>	<b>DATE CONSIDERED:</b> <i>7/21/04</i>
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U.S. PATENT DOCUMENTS							
Examiner Initials		Document Number	Date	Name	Class	Sub Class	Filing Date
<i>SM</i>	AA	4,485,128	11/27/84	Dalal et al.	427	85	
	AB	6,326,311	12/4/01	Ueda et al.	438	694	
	AC	6,350,993	2/26/02	Chu et al.	257	19	
	AD	6,376,337	4/23/02	Wang et al.	438	478	
	AE	6,436,784	8/20/02	Allam	438	380	
	AF	6,501,092	12/31/02	Nikonov et al.	257	29	
	AG	6,566,679	5/20/03	Nikonov et al.	257	29	
	AH	6,621,097	9/16/03	Nikonov et al.	257	17	
	AI	2003/0162335	8/28/03	Yuki et al.	438	151	3/4/03
<i>SM</i>	AJ	2003/0215990	11/20/03	Fitzgerald et al.	438	172	3/14/03
	AK						
	AL						
	AM						
	AN						
	AO						

FOREIGN PATENT DOCUMENTS							
		Document Number	Date	Country	Class	Sub Class	Translation
<i>SM</i>	AP	61220339A	9/30/86	Japan	H01L21	322	English Abstract
<i>SM</i>	AQ	61145820A	7/3/86	Japan	H01L21	20	English Abstract
<i>SM</i>	AR	99/63580	12/9/99	WO	H01L3	00	n/a

EXAMINER:	<i>S. Smith</i>	DATE CONSIDERED:	<i>7/24/04</i>
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